TEM: Transimission Electron Microscopy (TEM) is a technique where an electron beam interacts and passes through a specimen. The electrons are emitted by a source and are focused and magnified by a system of magnetic lenses. The geometry of TEM is shown in figure below. The electron beam is confined by the two condenser lenses which also control the brightness of the beam, passes the condenser aperture and "hits" the sample surface. The electrons that are elastically scattered consist the transmitted beams, which pass through the objective lens. The objective lens forms the image display and the following apertures, the objective and selected area aperture are used to choose of the elastically scattered electrons that will form the image of the microscope. Finally, the beam goes to the magnifying system that is consisted of three lenses, the first and second intermediate lenses which control the magnification of the image and the projector lens. The formed image is shown either on a fluorescent screen or in monitor or both and is printed on a photographic film.



Optics

The lenses of a TEM allow for beam convergence, with the angle of convergence as a variable parameter, giving the TEM the ability to change magnification simply by modifying the amount of current that flows through the coil, quadrupole or hexapole.

Typically a TEM consists of three stages of lensing. The stages are the condensor lenses, the objective lenses, and the projector lenses. The condensor lenses are responsible for primary beam formation, whilst the objective lenses focus the beam that comes through the sample itself. The projector lenses are used to expand the beam onto the phosphor screen or other imaging device, such as film. The magnification of the TEM is due to the ratio of the distances between the specimen and the objective lens' image plane. Additional quad or hexapole lenses allow for the correction of asymmetrical beam distortions, known as <u>astigmatism</u> (unclean edges). It is noted that TEM optical configurations differ significantly with implementation, with manufacturers using custom lens configurations, such as in <u>spherical aberration</u> (correct focal point) corrected instruments, or TEMs utilising energy filtering to correct electron <u>chromatic aberration</u> (is a type of distortion in which there is a failure of a lens to focus all color to the same convergence point. It occurs because lenses have a different refractive index for different wavelength of light.).

Display

Imaging systems in a TEM consist of a phosphor screen, which may be made of fine (10–100 μ m) particulate zinc sulfide, for direct observation by the operator. Optionally, an image recording system such as film based or doped screen coupled CCDs camera. Typically these devices can be removed or inserted into the beam path by the operator as required.

Specimen stage



TEM sample support mesh "grid", with ultramicrotomy sections.

TEM specimen stage designs include airlocks to allow for insertion of the specimen holder into the vacuum with minimal increase in pressure in other areas of the microscope. The specimen holders are adapted to hold a standard size of grid upon which the sample is placed or a standard size of self-supporting specimen. Standard TEM grid sizes are a 3.05 mm diameter ring, with a thickness and mesh size ranging from a few to 100 μ m. The sample is placed onto the inner meshed area having diameter of approximately 2.5 mm. Usual grid materials are copper, molybdenum, gold or platinum. This grid is placed into the sample holder, which is paired with the specimen stage. A wide variety of designs of stages and holders exist, depending upon the type of experiment being performed. In addition to 3.05 mm grids, 2.3 mm grids are sometimes, if rarely, used. These grids were particularly used in the mineral sciences where a large degree of tilt can be required. Electron transparent specimens have a thickness around 100 nm, but this value depends on the accelerating voltage.

Once inserted into a TEM, the sample often has to be manipulated to present the region of interest to the beam, such as in single <u>grain diffraction</u>, in a specific orientation. To accommodate this, the TEM stage includes mechanisms for the translation of the sample in the XY plane of the sample, for Z height adjustment of the sample holder, and usually for at least one rotation degree of freedom for the sample. <u>Thus a TEM stage may provide four degrees of freedom for the motion of the specimen</u>. Most modern TEMs provide the ability for two orthogonal rotation angles of movement with specialized holder designs called double-tilt sample holders. Of note however is that some stage designs, such as

top-entry or vertical insertion stages once common for high resolution TEM studies, may simply only have X-Y translation available. The design criteria of TEM stages are complex, owing to the simultaneous requirements of mechanical and electron-optical constraints and have thus generated many unique implementations.

A TEM stage is required to have the ability to hold a specimen and be manipulated to bring the region of interest into the path of the electron beam. As the TEM can operate over a wide range of magnifications, the stage must simultaneously be highly resistant to mechanical drift, with drift requirements as low as a few nm/minute while being able to move several µm/minute, with repositioning accuracy on the order of nanometers. Earlier designs of TEM accomplished this with a complex set of mechanical down gearing devices, allowing the operator to finely control the motion of the stage by several rotating rods. Modern devices may use electrical stage designs, using screw gearing in concert with stepper motors, providing the operator with a computer-based stage input, such as a joystick or trackball.

Two main designs for stages in a TEM exist, the side<u>-entry and top entry version</u>. Each design must accommodate the matching holder to allow for specimen insertion without either damaging delicate TEM optics or allowing gas into TEM systems under vacuum.



A diagram of a single axis tilt sample holder for insertion into a TEM goniometer. Titling of the holder is achieved by rotation of the entire goniometer

The most common is the side entry holder, where the specimen is placed near the tip of a long metal (brass or stainless steel) rod, with the specimen placed flat in a small bore. Along the rod are several polymer <u>vacuum rings</u> to allow for the formation of a vacuum seal of sufficient quality, when inserted into the stage. The stage is thus designed to accommodate the rod, placing the sample either in between or near the objective lens, dependent upon the objective design. When inserted into the stage, the side entry holder

has its tip contained within the TEM vacuum, and the base is presented to atmosphere, the airlock formed by the vacuum rings.

Insertion procedures for side-entry TEM holders typically involve the rotation of the sample to trigger <u>micro switches</u> that initiate evacuation of the airlock before the sample is inserted into the TEM column.

The second design is the top-entry holder consists of a cartridge that is several cm long with a bore drilled down the cartridge axis. The specimen is loaded into the bore, possibly utilising a small screw ring to hold the sample in place. This cartridge is inserted into an airlock with the bore perpendicular to the TEM optic axis. When sealed, the airlock is manipulated to push the cartridge such that the cartridge falls into place, where the bore hole becomes aligned with the beam axis, such that the beam travels down the cartridge bore and into the specimen. Such designs are typically unable to be tilted without blocking the beam path or interfering with the objective lens.

Sample preparation

Sample preparation in TEM can be a complex procedure. TEM specimens are required to be at most hundreds of nanometers thick, the electron beam interacts readily with the sample, an effect that increases roughly with atomic number squared (z^2). High quality samples will have a thickness that is comparable to the <u>mean free path of the electrons</u> that travel through the samples, which may be only a <u>few tens of nanometers</u>. Preparation of TEM specimens is specific to the material under analysis and the desired information to obtain from the specimen. As such, many generic techniques have been used for the preparation of the required thin sections.

Materials that have dimensions small enough to be electron transparent, such as powders or nanotubes, can be quickly prepared by the deposition of a dilute sample containing the specimen onto support grids or films. In the biological sciences in order to withstand the instrument vacuum and facilitate handling, biological specimens can be fixated using <u>either a negative staining material such as uranyl acetate or by plastic embedding</u>. Alternately samples may be held at liquid nitrogen temperatures after embedding in <u>vitreous ice</u>. In material science and metallurgy the specimens tend to be naturally resistant to vacuum, but still must be prepared as a thin foil, or etched so some portion of the specimen is thin enough for the beam to penetrate.

Tissue sectioning



A diamond knife blade used for cutting ultrathin sections (typically 70 to 350 nm for transmission electron microscopy.

By passing samples over a glass or diamond edge, small, thin sections can be readily obtained using a semi-automated method. This method is used to obtain thin, minimally deformed samples that allow for the observation of tissue samples. Additionally inorganic samples have been studied, such as aluminium, although this usage is limited owing to the heavy damage induced in the less soft samples. To prevent charge build-up at the sample surface, tissue samples need to be coated with a thin layer of conducting material, such as carbon, where the coating thickness is several nanometers. This may be achieved via an electric arc deposition process using a sputter coating device.

Sample staining



A section of a cell of *Bacillus subtilis*, taken with a Tecnai T-12 TEM. The scale bar is 200 nm.

Details in light microscope samples can be enhanced by <u>stains</u> that absorb light; similarly TEM samples of biological tissues can <u>utilize high atomic number stains to enhance</u> <u>contrast</u>. The stain absorbs electrons or scatters part of the electron beam which otherwise <u>is projected onto the imaging system</u>. Compounds of heavy metals such as osmium , lead, uranium or gold (in immunogold ladelling) may be used prior to TEM observation to selectively deposit electron dense atoms in or on the sample in desired cellular or protein regions, requiring an understanding of how heavy metals bind to biological tissues.

Imaging methods

Imaging methods in TEM utilize the information contained in the electron waves exiting from the sample to form an image. The projector lenses allow for the correct positioning of this electron wave distribution onto the viewing system. According to the following equation the observed intensity of the image, I, can be approximated as proportional to the time-average amplitude (the maximum displacement of a periodic wave) of the electron wave functions, where the wave which form the exit beam is denoted by Ψ .

$$I(x) = \frac{k}{t_1 - t_0} \int_{t_0}^{t_1} \Psi \Psi^* \, dt$$

Different imaging methods therefore attempt to modify the electron waves exiting the sample in a form that is useful to obtain information with regards to the sample, or beam itself. From the previous equation, it can be deduced that the observed image depends not only on the amplitude of beam, but also on the phase of the electrons, although phase effects may often be ignored at lower magnifications. Higher resolution imaging requires thinner samples and higher energies of incident electrons. Therefore the sample can no longer be considered to be absorbing electrons, via a Beer's law effect, rather the sample can be modelled as an object that does not change the amplitude of the incoming electron wave function. Rather the sample modifies the phase of the incoming wave; this model is known as a <u>pure phase object</u>, for sufficiently thin specimens phase effects dominate the image, complicating analysis of the observed intensities. For example, to improve the contrast in the image the <u>TEM may be operated at a slight defocus to enhance contrast</u>, owing to convolution (rotation) by the <u>contrast transfer function</u> of the TEM, which would normally decrease contrast if the sample was not a weak phase object.

Contrast formation

Contrast formation in the TEM depends greatly on the mode of operation. Complex imaging techniques, which utilise the unique ability to change lens strength or to deactivate a lens, allow for many operating modes. These modes may be used to discern information that is of particular interest to the investigator.

Bright field

The most common mode of operation for a TEM is the bright field imaging mode. In this mode the contrast formation is formed directly by occlusion (blocking) and absorption of electrons in the sample. Thicker regions of the sample, or regions with a higher atomic number will appear dark, whilst regions with no sample in the beam path will appear bright – hence the term "bright field". The image is in effect assumed to be a simple two dimensional projection of the sample down the optic axis, and to a first approximation may be modelled via <u>Beer's law</u>, more complex analyses require the modelling of the sample to include phase information.

Diffraction contrast



Transmission electron micrograph of dislocations in steel, which are faults in the structure of the crystal lattice at the atomic scale

Samples can exhibit diffraction contrast, whereby the electron beam undergoes scattering, which in the case of a crystalline sample, disperses electrons into separate locations in the back focal plane. By the placement of apertures in the back focal plane, i.e. the objective aperture, the desired reflections can be selected (or excluded), <u>thus only parts of the sample that are causing the electrons to scatter to the selected reflections will end up projected onto the imaging apparatus</u>.

If the reflections that are selected do not include the unscattered beam (which will appear up at the focal point of the lens), then the image will appear dark wherever no sample scattering to the selected peak is present, as such a region without a specimen will appear dark. This is known as a dark-field image.

Modern TEMs are often equipped with specimen holders that allow the user to tilt the specimen to a range of angles in order to obtain specific diffraction conditions, and apertures placed above the specimen allow the user to select electrons that would otherwise be diffracted in a particular direction from entering the specimen.

Applications for this method include the identification of lattice defects in crystals. By carefully selecting the orientation of the sample, it is possible not just to determine the position of defects but also to determine the type of defect present. If the sample is oriented so that one particular plane is only slightly tilted away from the strongest diffracting angled, any distortion of the crystal plane that locally tilts the plane to the

diffracting angle will produce particularly strong contrast variations. However, defects that produce only displacement of atoms that do not tilt the crystal to the diffracting angle (i. e. displacements parallel to the crystal plane) will not produce strong contrast.

Electron energy loss

Utilizing the advanced technique of EELS, for TEMs appropriately equipped electrons can be rejected based upon their voltage (which, due to constant charge is their energy), using magnetic sector based devices known as EELS spectrometers. These devices allow for the selection of particular energy values, which can be associated with the way the electron has interacted with the sample. For example different elements in a sample result in different electron energies in the beam after the sample. This normally results in chromatic aberration – however this effect can, for example, be used to generate an image which provides information on elemental composition, based upon the atomic transition during electron-electron interaction.

Phase contrast

Crystal structure can also be investigated by high-resolution transmission electron microscopy (HRTEM), also known as phase contrast. When utilizing a Field emission source and a specimen of uniform thickness, the images are formed due to differences in phase of electron waves, which is caused by specimen interaction. Image formation is given by the incoming electron beams. As such, the image is not only dependent on the number of electrons hitting the screen, making direct interpretation of phase contrast images more complex, but on phase of electron waves as well. However this effect can be used to an advantage, as it can be manipulated to provide more information about the sample.

Diffraction



Crystalline diffraction pattern from a twinned grain of steel

Diffraction pattern can be generated by adjusting the magnetic lenses such that the back focal plane of the lens rather than the imaging plane is placed on the imaging apparatus. For thin crystalline samples, this produces an image that consists of a pattern of dots in the case of a single crystal, or a series of rings in the case of a polycrystalline or amorphous solid material. For the single crystal case the <u>diffraction pattern is dependent</u> upon the orientation of the specimen and the structure of the sample illuminated by the <u>electron beam</u>. This image provides the investigator with information about the space group symmetries in the crystal and the crystal's orientation to the beam path. This is typically done without utilizing any information but the position at which the diffraction spots appear and the observed image symmetries.

Diffraction patterns can have a large dynamic range, and for crystalline samples, may have intensities greater than those recordable by CCD. As such, TEMs may still be equipped with film cartridges for the purpose of obtaining these images, as the film is a single use detector.



Convergent-beam Kikuchi lines from silicon, near the [100]

Analysis of diffraction patterns beyond point-position can be complex, as the image is sensitive to a number of factors such as specimen thickness and orientation, objective lens defocus, spherical and chromatic aberration. Although quantitative interpretation of the contrast shown in lattice images is possible, it is inherently complicated and can require extensive computer simulation and analysis, such as electron multislice analysis.

Three-dimensional imaging



A three-dimensional TEM image of a parapoxa virus

As TEM specimen holders typically allow for the rotation of a sample by a desired angle, multiple views of the same specimen can be obtained by rotating the angle of the sample along an axis perpendicular to the beam. By taking multiple images of a single TEM sample at differing angles, typically in 1° increments, a set of images known as a "tilt series" can be collected. This methodology was proposed in the 1970s by <u>Walter Hoppe</u>. Under purely absorption contrast conditions, this set of images can be used to construct a three-dimensional representation of the sample.

As TEM samples cannot typically be viewed at a full 180° rotation, the observed images typically suffer from a "missing wedge" of data, which when using methods decreases the range of resolvable frequencies in the three-dimensional reconstruction. Mechanical refinements, such as multi-axis tilting (two tilt series of the same specimen made at orthogonal directions) and conical tomography (where the specimen is first tilted to a given fixed angle and then imaged at equal angular rotational increments through one complete rotation in the plane of the specimen grid) can be used to limit the impact of the missing data on the observed specimen morphology. In addition, numerical techniques exist which can improve the collected data.